

# Advance Technical Information

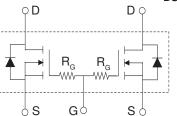
# TrenchMV<sup>™</sup> Power MOSFETs Common-Gate Pair

IXTL2x200N085T

 $V_{DSS} = 85 V$  $I_{D25} = 2x112 A$  $R_{DS(on)} \le 6.0 m\Omega$ 

(Electrically Isolated Back Surface)

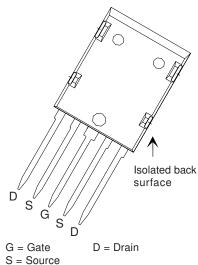
N-Channel Enhancement Mode Avalanche Rated



ISOPLUS i5-Pak™ (IXTL)

Symbol	Test Conditions	Maximum Ratings		
V <sub>DSS</sub> V <sub>DGR</sub>	$T_J$ = 25°C to 175°C $T_J$ = 25°C to 175°C; $R_{GS}$ = 1 M $\Omega$	85 85	V V	
V <sub>GSM</sub>	Transient	± 20	V	
I <sub>D25</sub>	$T_{c} = 25^{\circ}C$ (Combined die total = 224 A)	112	Α	
LRMS	Package Current Limit, RMS (Combined die total = 150 A)	75	Α	
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, pulse width limited by $T_{\rm JM}$	540	Α	
I <sub>AR</sub> E <sub>AS</sub>	$T_{c} = 25^{\circ}C$ $T_{c} = 25^{\circ}C$	25 1.0	A J	
dv/dt	$I_{_{S}} \leq I_{_{DM}}$ , di/dt $\leq$ 100 A/ $\mu$ s, $V_{_{DD}} \leq V_{_{DSS}}$ $T_{_{J}} \leq$ 175°C, $R_{_{G}} = 5 \Omega$	3	V/ns	
$P_{D}$	T <sub>c</sub> = 25°C	150	W	
T <sub>JM</sub> T <sub>stg</sub>		-55 +175 175 -55 +175	°C °C °C	
T <sub>L</sub> T <sub>SOLD</sub>	1.6 mm (0.062 in.) from case for 10 s Plastic body for 10 seconds	300 260	°C	
V <sub>ISOL</sub>	50/60 Hz, t = 1 minute, I <sub>ISOL</sub> < 1 mA, RMS	2500	V	
F <sub>c</sub>	Mounting force	20120/4.525	N/lb.	
Weight		9	g	

Symbol (T <sub>J</sub> = 25°C t	Test Conditions unless otherwise specified)	C Min	 stic Values Max.
BV <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, I_{D} = 250 \mu\text{A}$	85	V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.0	4.0 V
GSS	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$		± 200 nA
I <sub>DSS</sub>	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T <sub>J</sub> = 150°C	5 μA 250 μA
R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}, \text{ Note}$	es 1, 2	6.0 m Ω



#### **Features**

- Ultra-low On Resistance
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect
- 175 °C Operating Temperature

## **Advantages**

- Easy to mount
- Space savings
- High power density

#### **Applications**

- Automotive
- Motor Drives
- 42V Power Bus
- ABS Systems
- DC/DC Converters and Off-line UPS
- Primary Switch for 24V and 48V Systems
- High Current Switching Applications

All ratings and parametric values are per each MOSFET die unless otherwise specified.





Symbol	Test Conditions $(T_{_J} = 25^{\circ}\text{C u}$		racterist otherwis   Typ.		ecified)
g <sub>fs</sub>	V <sub>DS</sub> = 10 V; I <sub>D</sub> = 60 A, Note 1	75	125		S
$R_{g}$			3		Ω
C <sub>iss</sub>			7600		pF
C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		1040		pF
$\mathbf{C}_{rss}$			200		pF
t <sub>d(on)</sub>			32		ns
t,	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 25 \text{ A}$		80		ns
$\mathbf{t}_{d(off)}$	$R_{G} = 5 \Omega \text{ (External)}$		65		ns
t,			64		ns
<b>Q</b> <sub>g(on)</sub>			152		nC
$Q_{gs}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 25 \text{ A}$		37		nC
$\mathbf{Q}_{gd}$			42		nC
R <sub>thJC</sub>				1.0	°C/W
R <sub>thCS</sub>			0.50		°C/W

#### Source-Drain Diode

**Characteristic Values** T<sub>1</sub> = 25°C unless otherwise specified)

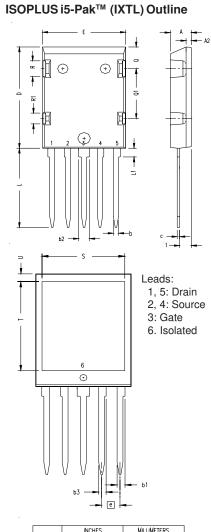
Symbol	Test Conditions	Min.	Тур.	Max.	
I <sub>s</sub>	$V_{GS} = 0 V$			200	Α
I <sub>SM</sub>	Pulse width limited by $T_{JM}$			540	Α
$\mathbf{V}_{\mathtt{SD}}$	$I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}, \text{ Note 1}$			1.0	V
t <sub>rr</sub>	$I_F = 25 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}$		55		ns
	$V_R = 40 \text{ V}, V_{GS} = 0 \text{ V}$				

Notes: 1. Pulse test:  $t \le 300 \mu s$ , duty cycle d  $\le 2 \%$ ;

2. Drain and Source Kelvin contacts must be located less than 5 mm from the plastic body.

### **ADVANCETECHNICALINFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.



out/	INCHES		MILLIMETERS		
SYM	MIN	MAX	MIN	MAX	
A	.190	.205	4.83	5.21	
A1	.102	.118	2.59	3.00	
A2	.046	.055	1.17	1.40	
b	.045	.055	1,14	1.40	
b1	.063	.072	1.60	1.83	
b2	.100	.110	2.54	2.79	
b3	.058	.068	1,47	1.73	
С	.020	.029	0.51	0.74	
D	1.020	1.040	25.91	26.42	
E	.770	.799	19.56	20.29	
e	.150 E	BSC .	3.81 BSC		
L	.780	.820	19.81 20.83		
L1	.080	.102	2.03	2.59	
Q	.210	.235	5.33	5.97	
Q1	.490	.513	12.45	13.03	
R	.150	.180	3.81	4.57	
R1	.100	.130	2.54	3.30	
S	.668	.690	16.97	17.53	
T	.801	.821	20.34	20.85	
U	.065	.080	1.65	2.03	

#### Note:

- 1. TAB 6 Electrically isolated from the other pins.
- 2. All leads and tab are tin plated.

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